



FSS264 — N-Channel Silicon MOSFET

General-Purpose Switching Device Applications

Features

- Low ON-resistance.
- 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		100	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		4	A
Drain Current (PW≤10s)	I _D	Duty cycle≤1%	5	A
Drain Current (PW≤10μs)	I _{DP}	Duty cycle≤1%	16	A
Allowable Power Dissipation	P _D	Mounted on a ceramic board (1200mm ² X0.8mm) PW≤10s	2.4	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =1mA, V _{GS} =0V	100			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _D =100V, V _{GS} =0V			1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _D =0V			±10	μA
Cutoff Voltage	V _{GS(off)}	V _D =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	y _{fs}	V _D =10V, I _D =2A	3.0	5.5		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =2A, V _{GS} =10V		65	85	mΩ
	R _{DS(on)2}	I _D =2A, V _{GS} =4V		80	112	mΩ
Input Capacitance	C _{iss}	V _D =20V, f=1MHz		1560		pF
Output Capacitance	C _{oss}	V _D =20V, f=1MHz		130		pF
Reverse Transfer Capacitance	C _{rss}	V _D =20V, f=1MHz		83		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit		16		ns
Rise Time	t _r	See specified Test Circuit		25		ns
Turn-OFF Delay Time	t _{d(off)}	See specified Test Circuit		155		ns
Fall Time	t _f	See specified Test Circuit		66		ns

Marking : S264

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SANYO Electric Co.,Ltd. Semiconductor Company

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

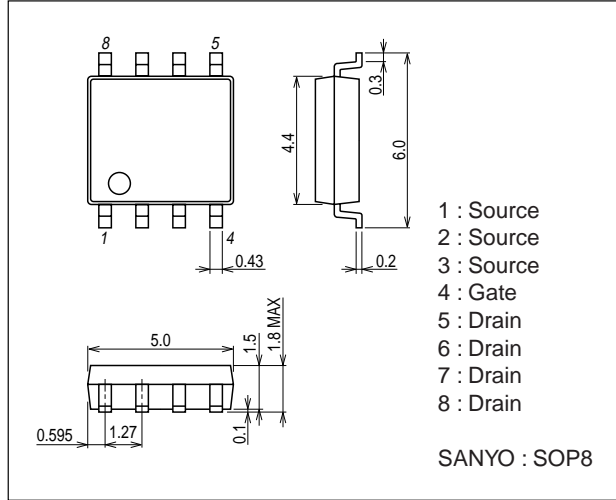
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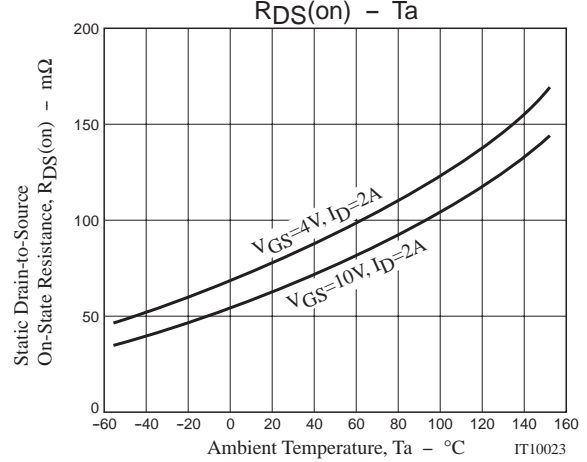
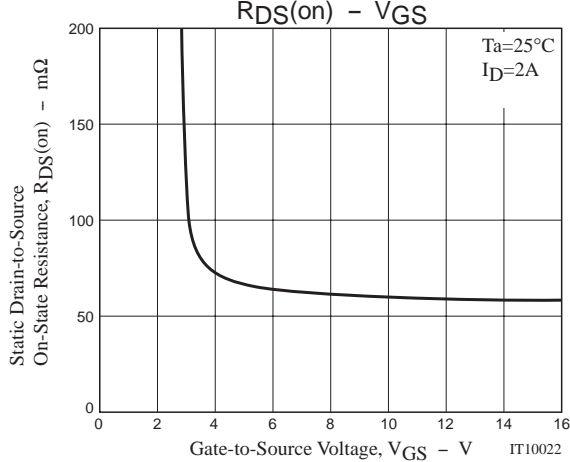
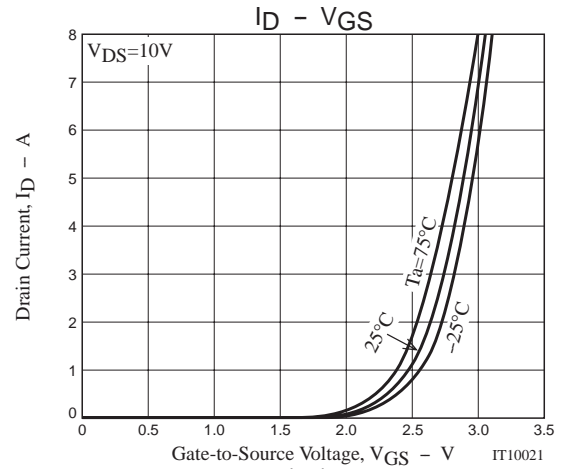
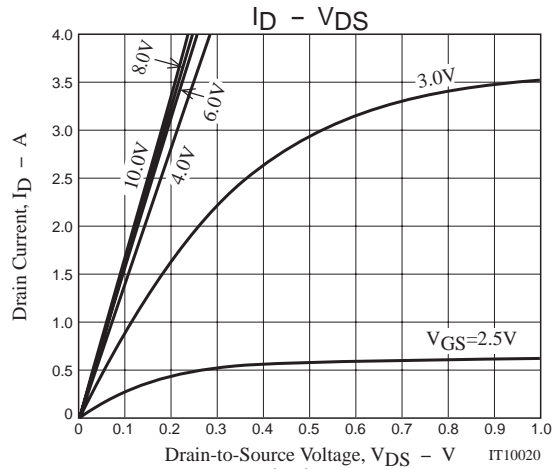
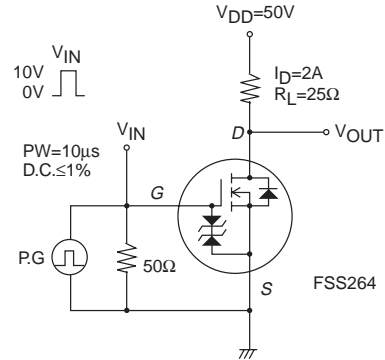
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Total Gate Charge	Qg	$V_{DS}=50V, V_{GS}=10V, I_D=4A$		34		nC
Gate-to-Source Charge	Qgs	$V_{DS}=50V, V_{GS}=10V, I_D=4A$		5.5		nC
Gate-to-Drain "Miller" Charge	Qgd	$V_{DS}=50V, V_{GS}=10V, I_D=4A$		6		nC
Diode Forward Voltage	VSD	$I_S=4A, V_{GS}=0V$		0.81	1.2	V

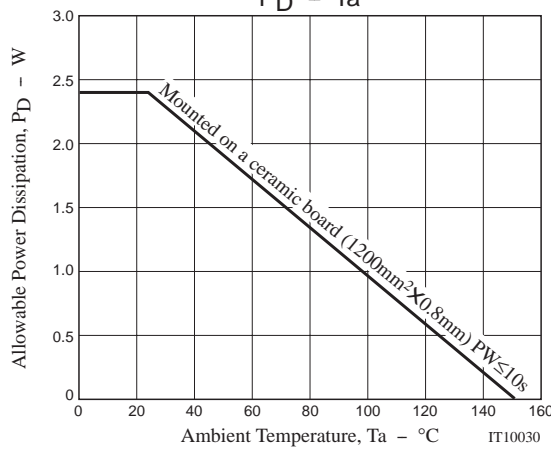
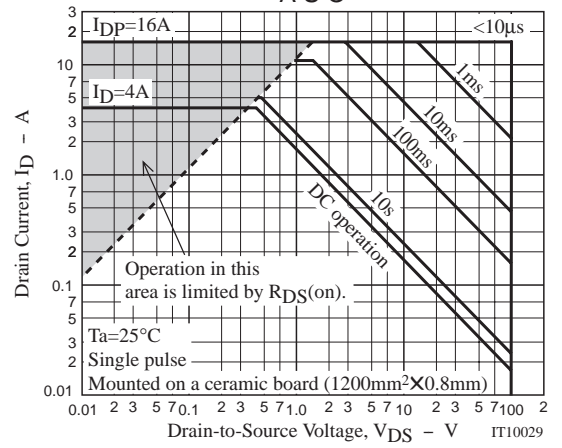
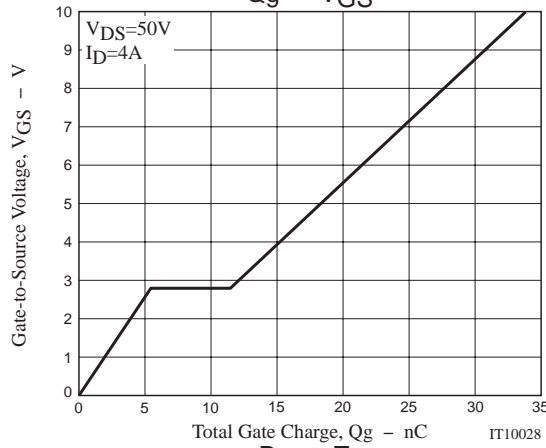
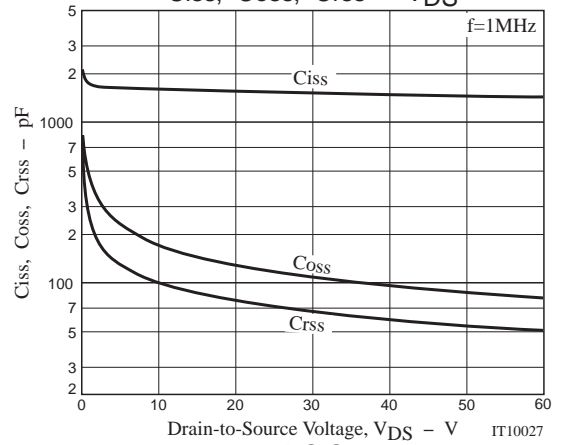
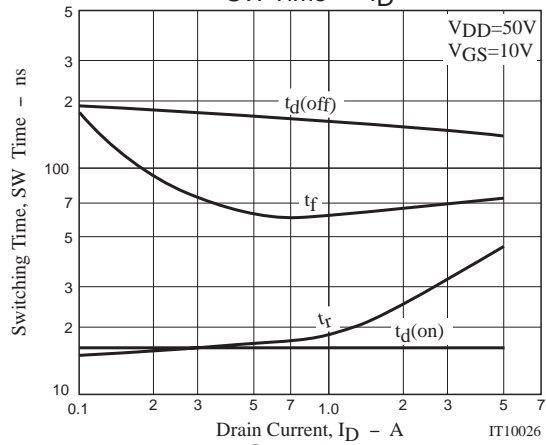
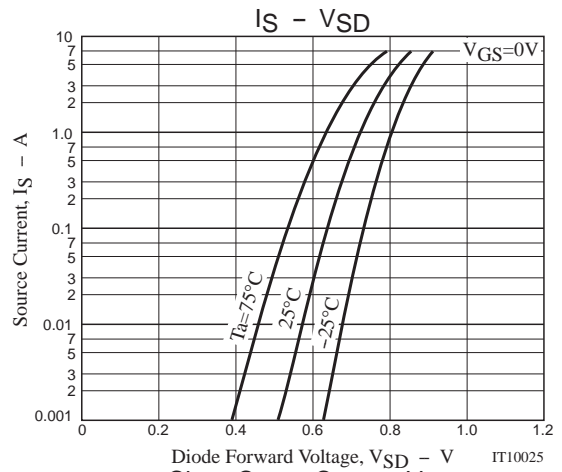
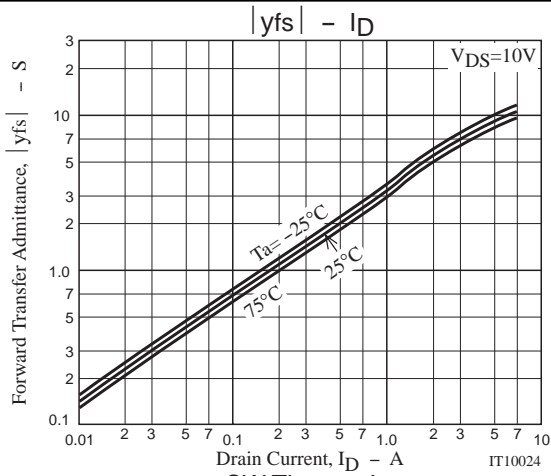
Package Dimensions

unit : mm
7005-002



Switching Time Test Circuit





Note on usage : Since the FSS264 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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